



2SJ499

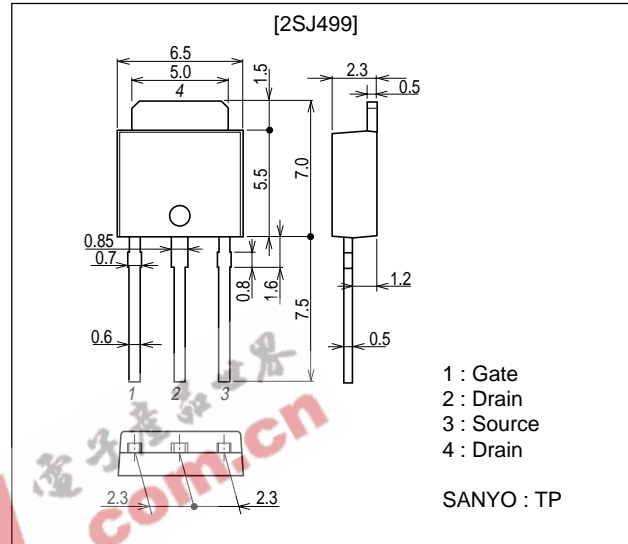
Load Switching Applications

Features

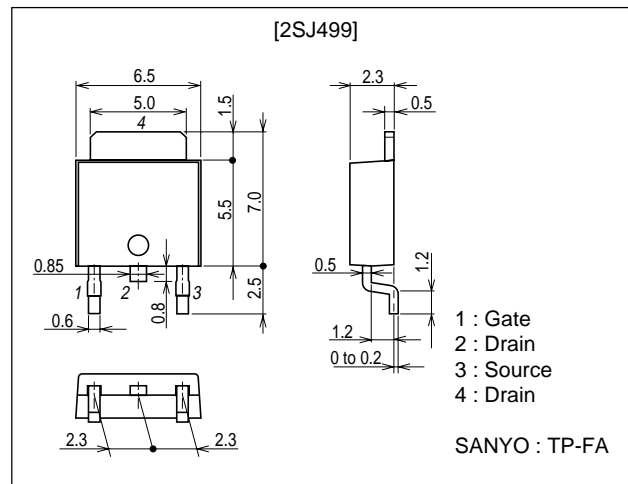
- Low ON-state resistance.
- 4V drive.

Package Dimensions

unit : mm
2083B



unit : mm
2092B



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Specifications

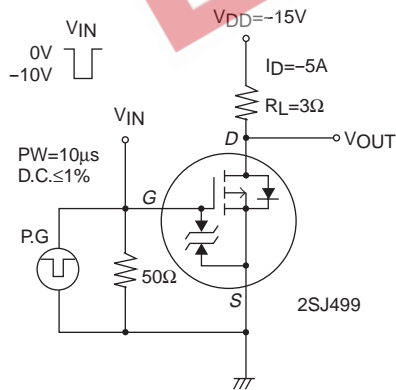
Absolute Maximum Ratings at Ta=25°C

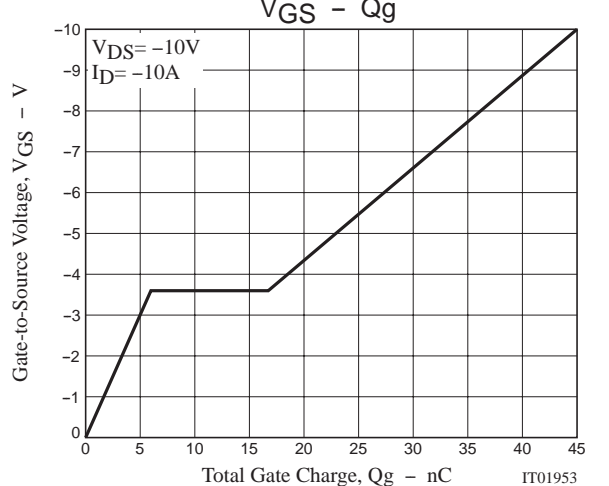
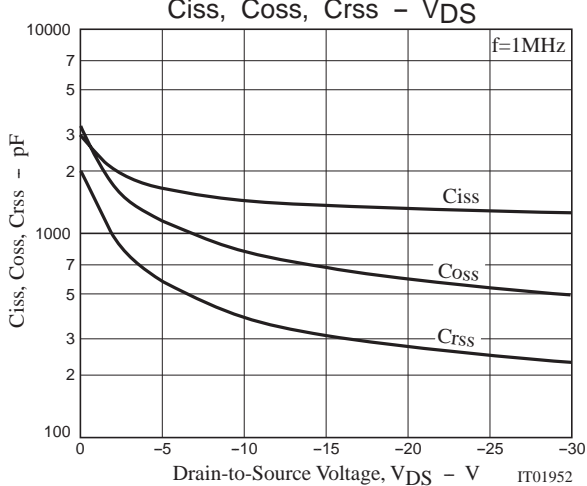
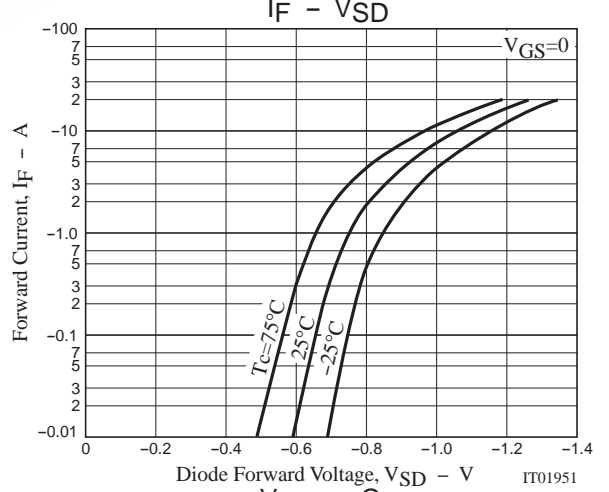
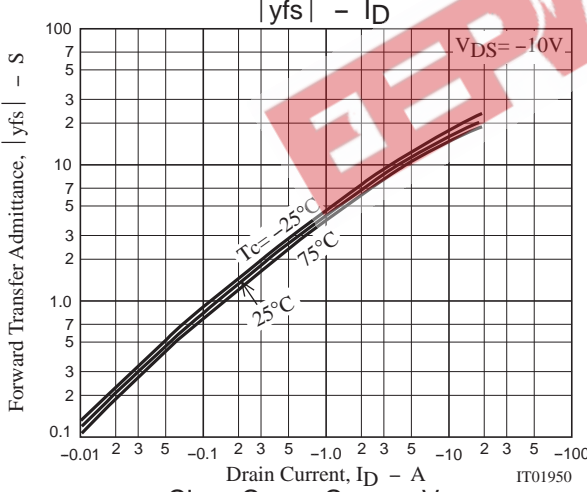
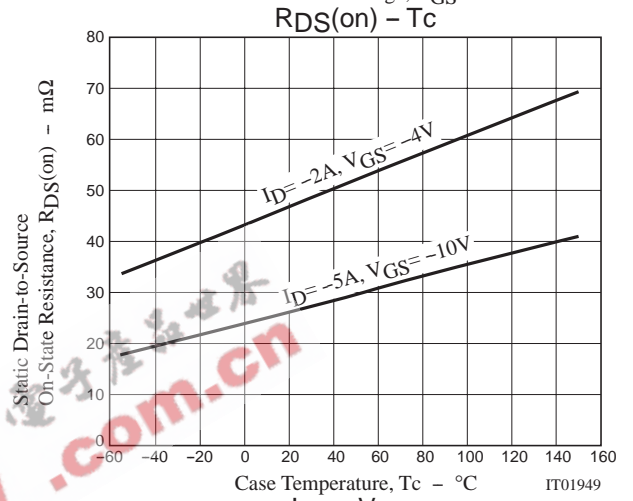
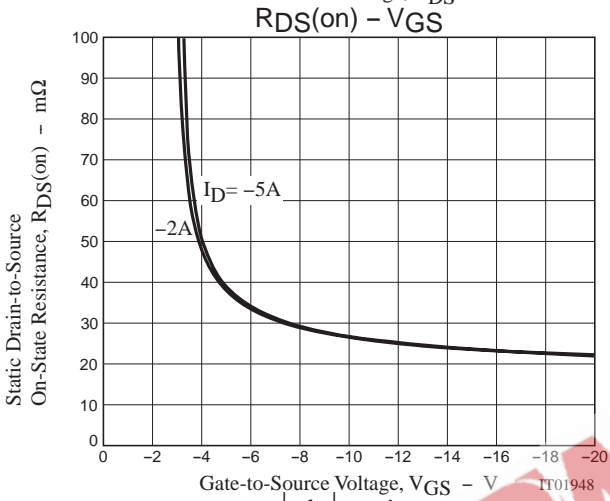
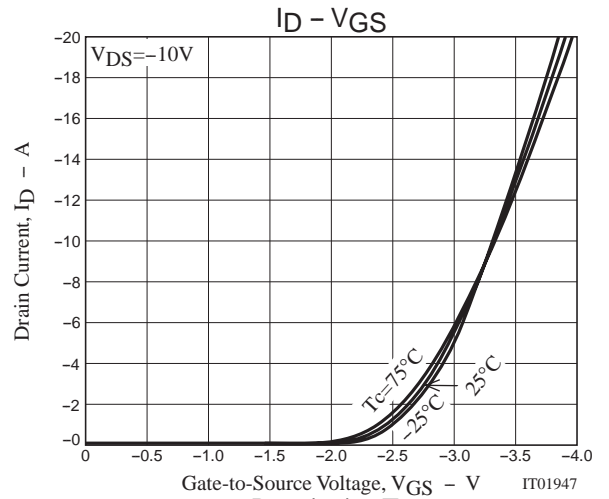
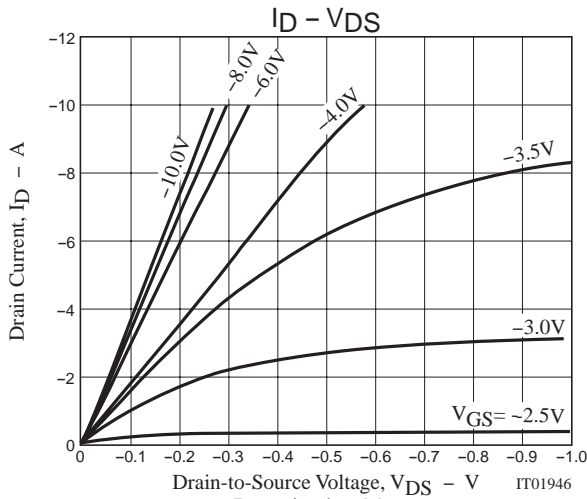
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-30	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		-10	A
Drain Current (Pulse)	I _{DP}	PW≤10ms, duty cycle≤1%	-32	A
Allowable Power Dissipation	PD		1.0	W
		T _c =25°C	30	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

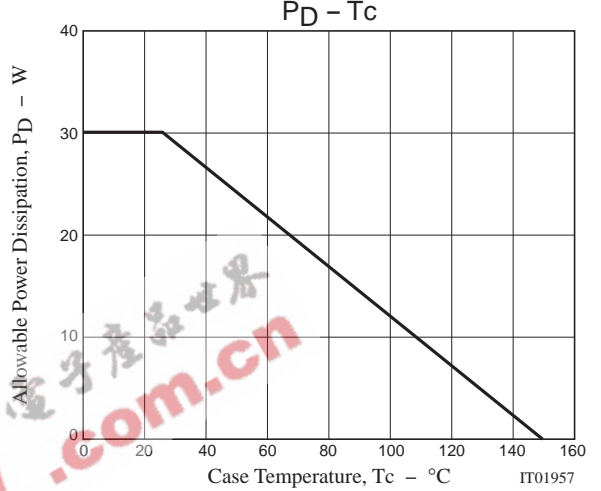
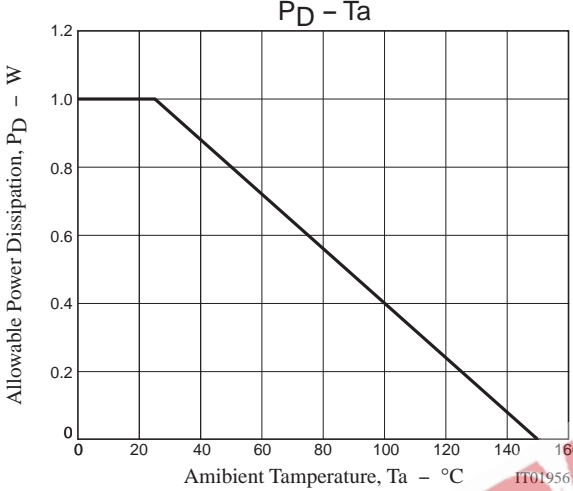
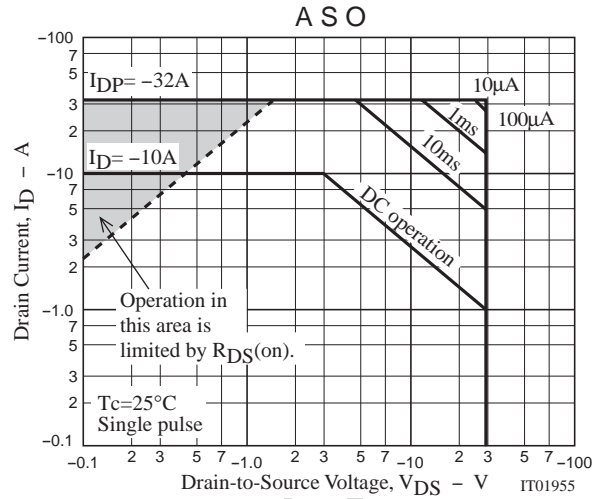
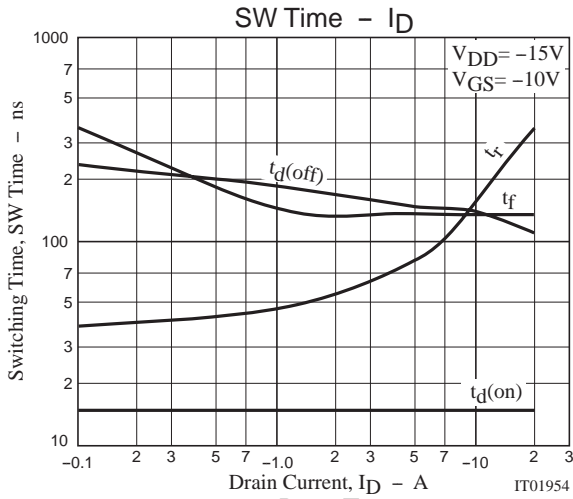
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =-1mA, V _{GS} =0	-30			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0			-10	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-1.0		-2.5	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-5A	8	10		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-5A, V _{GS} =-10V		27	45	mΩ
	R _{DS(on)2}	I _D =-2A, V _{GS} =-4V		48	68	mΩ
Input Capacitance	C _{iss}	V _{DS} =-10V, f=1MHz		1500		pF
Output Capacitance	C _{oss}	V _{DS} =-10V, f=1MHz		800		pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} =-10V, f=1MHz		370		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit		15		ns
Rise Time	t _r	See specified Test Circuit		80		ns
Turn-OFF Delay Time	t _{d(off)}	See specified Test Circuit		150		ns
Fall Time	t _f	See specified Test Circuit		140		ns
Total Gate Charge	Q _g	V _{DS} =-10V, V _{GS} =-10V, I _D =-10A		45		nC
Gate-to-Source Charge	Q _{gs}	V _{DS} =-10V, V _{GS} =-10V, I _D =-10A		6		nC
Gate-to-Drain "Miller" Charge	Q _{gd}	V _{DS} =-10V, V _{GS} =-10V, I _D =-10A		11		nC
Diode Forward Voltage	V _{SD}	I _S =-5A, V _{GS} =0	-0.9		-1.2	V

Switching Time Test Circuit







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